

IXFN21N100Q Datasheet



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DiGi Electronics Part Number IXFN21N100Q-DG

Manufacturer IXYS

Manufacturer Product Number IXFN21N100Q

Description MOSFET N-CH 1000V 21A SOT-227B

Detailed Description N-Channel 1000 V 21A (Tc) 520W (Tc) Chassis Moun

t SOT-227B



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
IXFN21N100Q	IXYS
Series:	Product Status:
HiPerFET™, Q Class	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (Id) @ 25°C:
1000 V	21A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ Id, Vgs:
10V	500mOhm @ 500mA, 10V
Vgs(th) (Max) @ Id:	Gate Charge (Qg) (Max) @ Vgs:
5V @ 4mA	170 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	5900 pF @ 25 V
FET Feature:	Power Dissipation (Max):
	520W (Tc)
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Chassis Mount
Supplier Device Package:	Package / Case:
SOT-227B	SOT-227-4, miniBLOC
Base Product Number:	
IXFN21	

Environmental & Export classification

8541.29.0095

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



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